NSN 5961-01-362-6703

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-362-6703 **Inclosure Material:** Metal **Overall Length:** Between 0.630 inches and 0.710 inches **Overall Diameter:** Between 0.280 inches and 0.290 inches Lens Transparency: Transparent all semiconductor **Component Name And Quantity:** 6 light emitting diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor Voltage Rating In Volts Per Characteristic: 28.0 forward voltage, dc all light emitting diode **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current preset single light emitting diode **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-emitter peak all light emitting diode **Color Tone Produced Per Source:** Red lens all semiconductor **Luminous Intensity:** 15.0 millicandela all light emitting diode **Terminal Type And Quantity:** 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No